Diode Module

# **STARPOWER**

SEMICONDUCTOR

# **Rectifier Diode**

# **RD80HFS180C9S**

**Molding Type Module** 

1800V/80A 2 in one-package

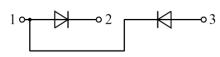


### **General Description**

STARPOWER Rectifier Diode Power Module provides ultra low conduction loss. They are designed for the applications such as SMPS.

#### Features

- Low forward voltage drop
- Small temperature coefficient
- High Surge Capacity
- Low inductance
- Isolated Copper Baseplate Using DBC Technology



Equivalent Circuit Schematic

### **Typical Applications**

- Input bridge rectifier
- AC/DC motor control
- Power supply

Symbol	Description	RD80HFS180C9S	Units	
V <sub>RRM</sub>	Repetitive Peak Reverse Voltage	1800	V	
V <sub>RSM</sub>	Non-repetitive Peak Reverse Voltage	1800	V	
I <sub>FAV</sub>	Average Forward Current $T_C=100^{\circ}C$	80	Α	
I <sub>FSM</sub>	Surge Forward Current $V_R=0V_{,t_p}=10m_{,t_j}=45^{\circ}C$	1100	А	
	$V_R=0V, t_p=8.3 \text{ms}, T_j=45 ^{\circ}\text{C}$	1200		
I <sup>2</sup> t	$I^2$ t-value $V_R=0V, t_p=10ms, T_j=45^{\circ}C$	6050	A <sup>2</sup> s	
	$V_R=0V, t_p=8.3 \text{ms}, T_j=45^{\circ}\text{C}$	6000		
P <sub>D</sub>	Maximum Power Dissipation @ T <sub>j</sub> =150°C	212	W	
Tj	Junction Temperature	-40 to +150	°C	
T <sub>STG</sub>	Storage Temperature Range	-40 to +125	°C	
V <sub>ISO</sub>	Isolation Voltage RMS,f=50Hz,t=1min	4000	V	
М	Terminal Connection Torque, Screw M5	2.5 to 5.0	N.m	
	Mounting Torque, Screw M5	3.0 to 5.0		

### Absolute Maximum Ratings $T_C=25$ °C unless otherwise noted

**Electrical Characteristics of Diode**  $T_C=25$  °C unless otherwise noted

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
$V_{\rm F}$	Diode Forward	I <sub>F</sub> =150A	Tj=25℃			1.31	v
	Voltage		T <sub>j</sub> =150℃			1.28	
I <sub>R</sub>	Diode Reverse	V <sub>R</sub> =V <sub>RRM</sub>	T <sub>i</sub> =25℃			0.05	mA
	Current		T <sub>j</sub> =150°C			2.00	

### **Thermal Characteristics**

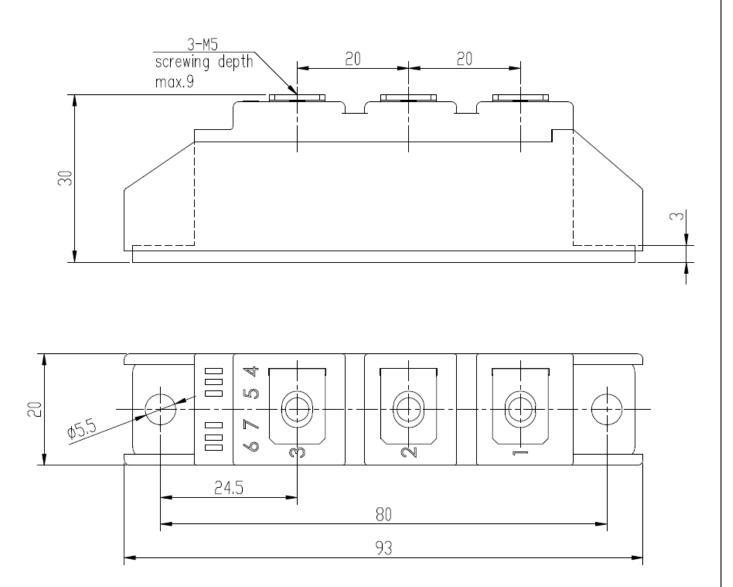
Symbol	Parameter	Тур.	Max.	Units
$R_{\theta JC}$	Junction-to-Case (per Diode)		0.591	K/W
$R_{\theta CS}$	Case-to-Sink (Conductive grease applied)	0.1		K/W
Weight	Weight of Module	95		g

#### RD80HFS180C9S

Diode Module

### **Package Dimensions**

Dimensions in Millimeters



#### **Terms and Conditions of Usage**

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